



MICROCIRCUIT DATA SHEET

MV54ACT175-X REV 0A0

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Quad D Flip-Flop

General Description

The 54ACT175 is a high-speed quad D flip-flop. The device is useful for general flip-flop requirements where clock and clear inputs are common. The information on the D inputs is stored during the LOW-to-HIGH clock transition. Both true and complemented outputs of each flip-flop are provided. A Master Reset input resets all flip-flops, independent of the Clock or D inputs, when LOW.

Industry Part Number

54ACT175

NS Part Numbers

54ACT175E-QMLV*
54ACT175J-QMLV**
54ACT175W-QMLV***

Prime Die

J175

Controlling Document

5962-89693

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp Description

Subgrp	Description	Temp (°C)
1	Static tests at	+25 C
2	Static tests at	+125 C
3	Static tests at	-55 C
4	Dynamic tests at	+25 C
5	Dynamic tests at	+125 C
6	Dynamic tests at	-55 C
7	Functional tests at	+25 C
8A	Functional tests at	+125 C
8B	Functional tests at	-55 C
9	Switching tests at	+25 C
10	Switching tests at	+125 C
11	Switching tests at	-55 C

Features

- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- Asynchronous common reset
- True and complement output
- Outputs source/sink 24 mA
- ACT175 has TTL-compatible inputs
- Standard Military Drawing (SMD)
- ACT175: 5962-8969301V2A*, VEA**, VFA***

(Absolute Maximum Ratings)

(Note 1)

Supply Voltage (Vcc)	-0.5V to +7.0V
DC Input Diode Current (Iik) Vi = -0.5V Vi = Vcc +0.5V	-20 mA +20 mA
DC Input Voltage (Vi)	-0.5V to Vcc +0.5V
DC Output Diode Current (Iok) Vo = -0.5V Vo = Vcc +0.5V	-20 mA +20 mA
DC Output Voltage (Vo)	-0.5V to Vcc +0.5V
DC Output Source or Sink Current (Io)	\pm 50 mA
DC Vcc or Ground Current per Output Pin (Icc or Ignd)	\pm 50 mA
Storage Temperature (Tstg)	-65 C to +150 C
Junction Temperature (Tj) CDIP	175 C
Thermal Resistance, junction-to-case	See Mil-Std-1835
Maximum Power Dissipation (pd)	500 mW
Lead Temperature soldering, 10 seconds	+300C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT TM circuits outside databook specifications.

Recommended Operating Conditions

Supply Voltage (Vcc)	4.5V to 5.5V
Input Voltage (Vi)	0V to Vcc
Output Voltage (Vo)	0V to Vcc
Operating Temperature (Ta)	-55 C to +125 C
Minimum Input Edge Rate (Delta V/Delta t) ACT Devices Vin from 0.8V to 2.0V Vcc @ 4.5V, 5.5V	125 mV/ns

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
 DC: VCC 4.5V to 5.5V, Temp. Range: -55C to 125C.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
IIH	High Level Input Current	VCC=5.5V, VM=5.5V	1, 2	INPUT		0.1	uA	1
			1, 2	INPUT		1.0	uA	2, 3
IIL	Low Level Input Current	VCC=5.5V, VM=0.0V	1, 2	INPUT		-0.1	uA	1
			1, 2	INPUT		-1.0	uA	2, 3
VOL	Low Level Output Voltage	VCC=4.5V, IOL=50.0uA, VIL=0.8V, VIH=2.0V	1, 2	OUTPUT		.10	V	1, 2, 3
		VCC=5.5V, IOL=50.0uA, VIL=0.8V, VIH=2.0V	1, 2	OUTPUT		.10	V	1, 2, 3
		VCC=4.5V, IOL=24.0mA, VIL=0.8V, VIH=2.0V	1, 2	OUTPUT		.36	V	1
		VCC=5.5V, IOL=24.0mA, VIL=0.8V, VIH=2.0V	1, 2	OUTPUT		.36	V	1
			1, 2	OUTPUT		.50	V	2, 3
VIOL	Dynamic output current LOW	VCC=5.5V, VIL=0.8V, VIH=2.0V, IOL=50.0mA	1, 2, 5	OUTPUT		1.65	V	1, 2, 3
VOH	High Level Output Voltage	VCC=4.5V, VIL=0.8V, VIH=2.0V, IOH=-50.0uA	1, 2	OUTPUT	4.40		V	1, 2, 3
		VCC=5.5V, VIL=0.8V, VIH=2.0V, IOH=-50.0uA	1, 2	OUTPUT	5.40		V	1, 2, 3
		VCC=4.5V, VIL=0.8V, VIH=2.0V, IOH=-24.0mA	1, 2	OUTPUT	3.86		V	1
		VCC=5.5V, VIL=0.8V, VIH=2.0V, IOH=-24.0mA	1, 2	OUTPUT	3.70		V	2, 3
			1, 2	OUTPUT	4.86		V	1
			1, 2	OUTPUT	4.70		V	2, 3
VIOH	Dynamic output current HIGH	VCC=5.5V, VIL=0.8V, VIH=2.0V, IOH=-50.0mA	1, 2, 5	OUTPUT	3.85		V	1, 2, 3
ICCH	Supply Current Outputs HIGH	VCC=5.5V	1, 2	VCC		100	nA	1
			1, 2	VCC		160	uA	2, 3
ICCL	Supply Current Outputs LOW	VCC=5.5V	1, 2	VCC		100	nA	1
			1, 2	VCC		160	uA	2, 3
ICCF	Supply Current Functional	VCC=5.5V	1, 2	VCC		100	nA	1
			1, 2	VCC		160	uA	2, 3
ICCT	Supply Current per Input	VCC=5.5V, VIHT=VCC-2.1V	1, 2	VCC		1.0	mA	1
			1, 2	VCC		1.6	mA	2, 3
VIC-	Negative Input Clamp Voltage	VCC=Open, IM=-1.0mA	8, 9	INPUT	-0.40	-1.50	V	1

Electrical Characteristics

DC PARAMETERS (Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)
 DC: VCC 4.5V to 5.5V, Temp. Range: -55C to 125C.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
VIC+	Positive Input Clamp Voltage	VCC=0.0V, IM=1.0mA	8, 9	INPUT	0.40	1.5	V	1

Electrical Characteristics

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
 AC: CL=50pF, RL=500 OHMS, TRISE/TFALL=3.0ns, Temp Range: -55C to 125C.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
tpLH(1)	Propagation Delay	VCC=4.5V	3, 4, 7	CP to \bar{Q}_n or Q_n	1.5	10.0	ns	9
			3, 4, 7	CP to \bar{Q}_n or Q_n	1.5	11.5	ns	10, 11
tpHL(1)	Propagation Delay	VCC=4.5V	3, 4, 7	CP to \bar{Q}_n or Q_n	1.5	10.0	ns	9
			3, 4, 7	CP to \bar{Q}_n or Q_n	1.5	12.5	ns	10, 11
tpLH(2)	Propagation Delay	VCC=4.5V	3, 4, 7	\bar{M}_R to \bar{Q}_n or Q_n	1.5	9.5	ns	9
			3, 4, 7	\bar{M}_R to \bar{Q}_n or Q_n	1.5	11.5	ns	10, 11
tpHL(2)	Propagation Delay	VCC=4.5V	3, 4, 7	\bar{M}_R to \bar{Q}_n or Q_n	1.5	9.5	ns	9
			3, 4, 7	\bar{M}_R to \bar{Q}_n or Q_n	1.5	11.0	ns	10, 11
ts(H/L)	Setup Time HIGH or LOW	VCC=4.5V	6	D _n to CP	3.0		ns	9
			6	D _n to CP	3.5		ns	10, 11
th(H/L)	Setup Time HIGH or LOW	VCC=4.5V	6	D _n to CP	1.5		ns	9, 10, 11
tw(H/L)(1)	Pulse Width HIGH or LOW	VCC=4.5V	6	CP	5.0		ns	9, 10, 11
tw(L)(2)	MR Pulse Width LOW	VCC=4.5V	6	\bar{M}_R	5.0		ns	9, 10, 11
tREC	Recovery Time	VCC=4.5V	6	\bar{M}_R to CP	1.0		ns	9
			6	\bar{M}_R to CP	1.5		ns	10, 11
fMAX	Maximum Clock Frequency	VCC=4.5V	6		95		ns	9, 10, 11

Note 1: SCREEN TESTED 100% ON EACH DEVICE AT +25C & +125C TEMPERATURE, SUBGROUPS 1, 2, 7, & 8.

Note 2: SAMPLE TESTED (METHOD 5005, TABLE 1) ON EACH MFG. LOT AT +25C, +125C, & -55C TEMPERATURE, SUBGROUPS A1, 2, 3, 7, & 8.

Note 3: SCREEN TESTED 100% ON EACH DEVICE AT +25C TEMPERATURE ONLY, SUBGROUP A9.

(Continued)

- Note 4: SAMPLE TESTED (METHOD 5005, TABLE 1) ON EACH MFG. LOT AT +25C, +125C, & -55C TEMPERATURE, SUBGROUPS A9, 10 & 11.
- Note 5: TRANSMISSION LINE DRIVING TEST, GUARDBAND LIMITS SET FOR +25C, 2 MSEC DURATION MAX.
- Note 6: GUARANTEED BUT NOT TESTED. (DESIGN CHARACTERIZATION DATA)
- Note 7: MIN LIMITS GUARANTEED FOR 5.5V BY GUARDBANDING 4.5V MINIMUM LIMITS.
- Note 8: SCREEN TESTED 100% ON EACH DEVICE AT +25C TEMPERATURE ONLY, SUBGROUP A1.
- Note 9: SAMPLE TESTED (METHOD 5005, TABLE 1) AT +25C TEMPERATURE ONLY, SUBGROUP A1.